

### AUDIO FREQUENCY AMPLIFIER, SWITCHING PNP SILICON EPITAXIAL TRANSISTORS

#### FEATURES

- Low  $V_{CE(sat)}$   
 $V_{CE(sat)} = -0.15 \text{ V Max (@} I_c/I_B = 0.5 \text{ A/25 mA)}$
- High DC Current Gain  
 $h_{FE} = 150 \text{ to } 600 (@V_{CE} = -2.0 \text{ V, } I_c = -0.5 \text{ A})$

#### ABSOLUTE MAXIMUM RATINGS

Maximum Voltage and Current ( $T_A = 25 \text{ }^\circ\text{C}$ )

Collector to Base Voltage	$V_{CB0}$	-30 V
Collector to Emitter Voltage	$V_{CE0}$	-30 V
Emitter to Base Voltage	$V_{EB0}$	-6.0 V
Collector Current (DC)	$I_{C(DC)}$	-5.0 A
Collector Current (Pulse)*	$I_{C(Pulse)}$	-8.0 A
Base Current (DC)	$I_{B(DC)}$	-1.0 A

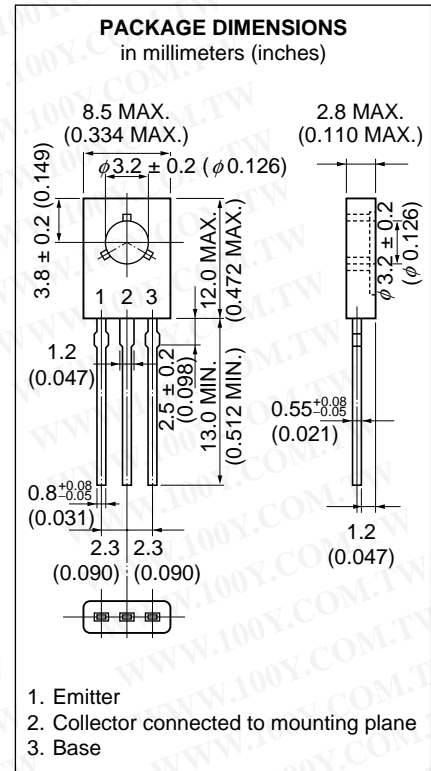
\* PW  $\leq$  10ms, Duty Cycle  $\leq$  10 %

Maximum Power Dissipation

Total Power Dissipation ( $T_C = 25 \text{ }^\circ\text{C}$ )	$P_T$	10 W
Total Power Dissipation ( $T_A = 25 \text{ }^\circ\text{C}$ )	$P_T$	1.0 W

Maximum Temperature

Junction Temperature	$T_j$	150 $^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to 150 $^\circ\text{C}$

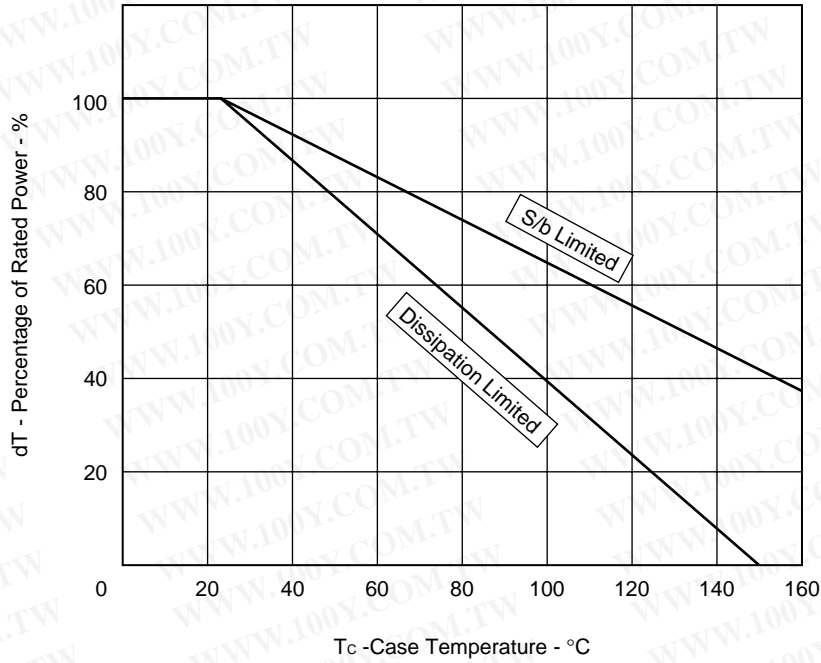


#### ELECTRICAL CHARACTERISTICS ( $T_A = 25 \text{ }^\circ\text{C}$ )

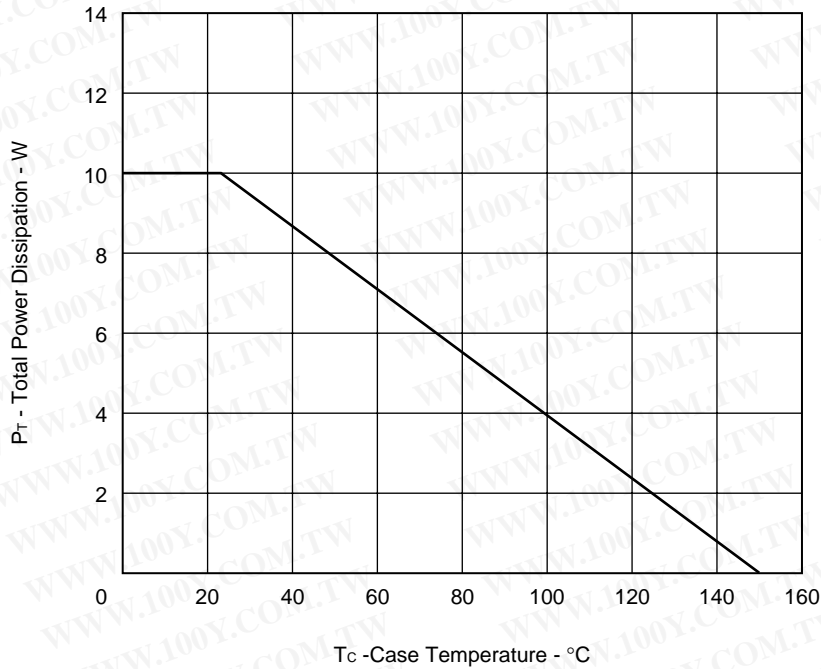
characteristics	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Collector Cutoff Current	$I_{CB0}$	$V_{CB} = -30 \text{ V, } I_E = 0$			-100	nA
Emitter Cutoff Current	$I_{EB0}$	$V_{EB} = -6.0 \text{ V, } I_C = 0$			-100	nA
DC Current Gain	$h_{FE1}$	$V_{CE} = -2.0 \text{ V, } I_c = -0.5 \text{ A}$	150		600	—
DC Current Gain	$h_{FE2}$	$V_{CE} = -2.0 \text{ V, } I_c = -3.0 \text{ A}$	70			—
Collector Saturation Voltage	$V_{CE(sat)1}$	$I_c = -0.5 \text{ A, } I_B = -25 \text{ mA}$		-0.08	-0.15	V
Collector Saturation Voltage	$V_{CE(sat)2}$	$I_c = -1.0 \text{ A, } I_B = -50 \text{ mA}$		-0.13	-0.25	V
Collector Saturation Voltage	$V_{CE(sat)3}$	$I_c = -2.0 \text{ A, } I_B = -100 \text{ mA}$		-0.24	-0.40	V
Collector Saturation Voltage	$V_{CE(sat)4}$	$I_c = -3.0 \text{ V, } I_B = -75 \text{ mA}$		-0.46	-1.0	V
Base Saturation Voltage	$V_{BE(sat)}$	$I_c = -1.0 \text{ A, } I_B = -50 \text{ mA}$		-0.83	-1.50	V
Gain Bandwidth Product	$f_r$	$V_{CE} = -10 \text{ V, } I_E = -50 \text{ mA}$		75		MHz
Output Capacitance	$C_{ob}$	$V_{CB} = -10 \text{ V, } I_E = 0, f = 1 \text{ MHz}$		60		pF

The information in this document is subject to change without notice.

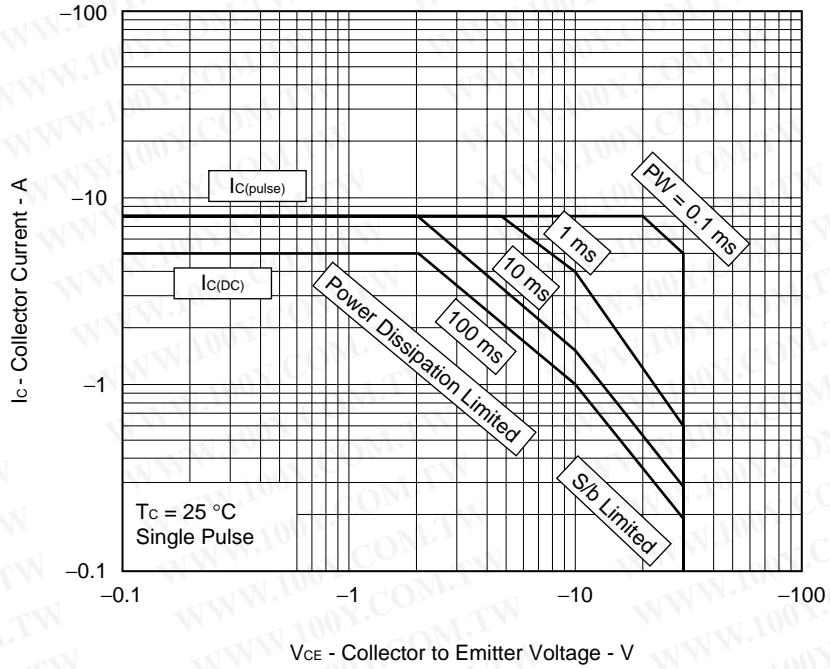
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

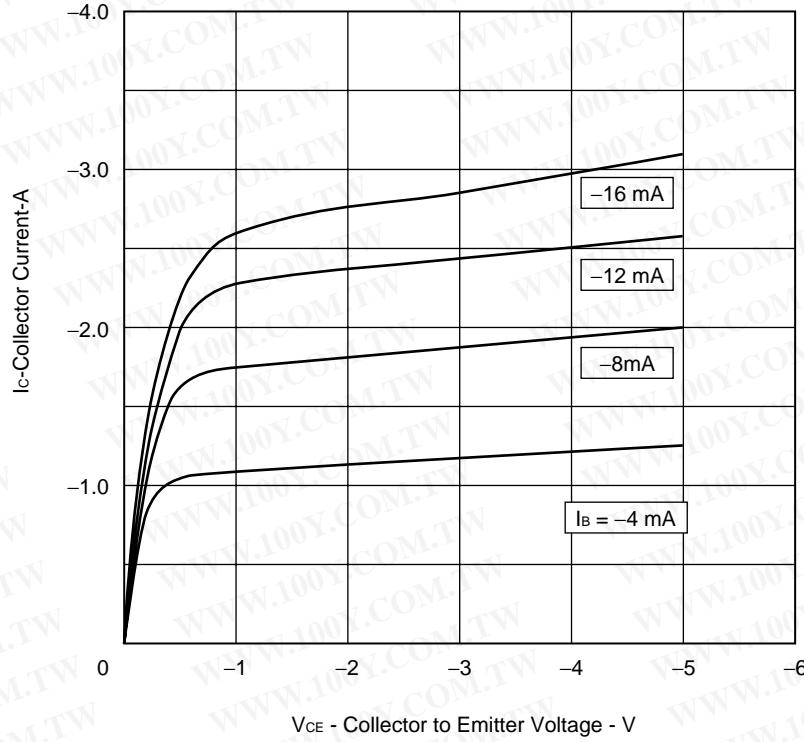


FORWARD BIAS SAFE OPERATING AREA

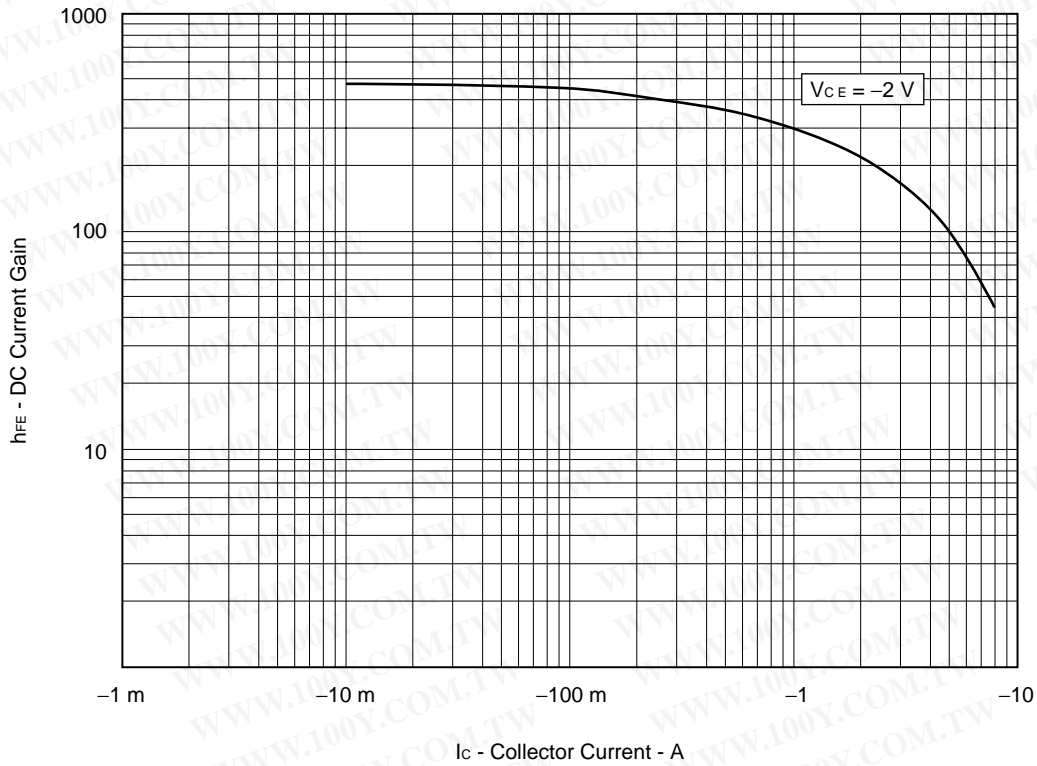


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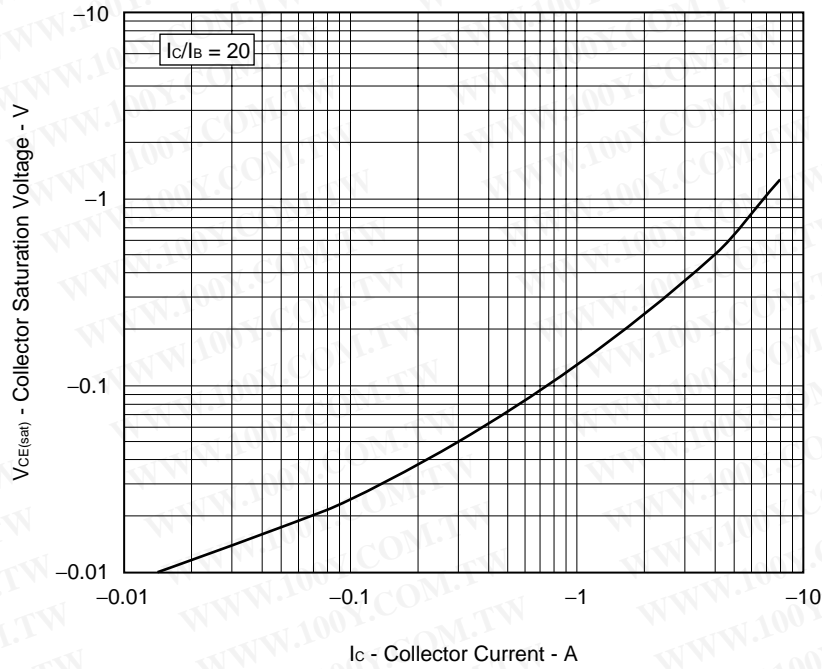
COLLECTOR TO EMITTER VOLTAGE vs COLLECTOR CURRENT



DC CURRENT GAIN vs COLLECTOR CURRENT

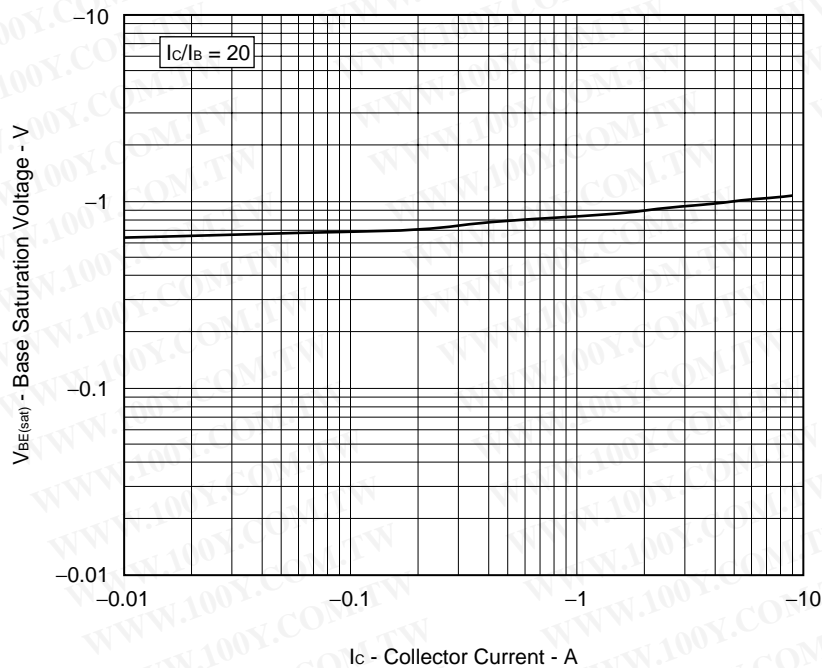


COLLECTOR SATURATION VOLTAGE vs COLLECTOR CURRENT



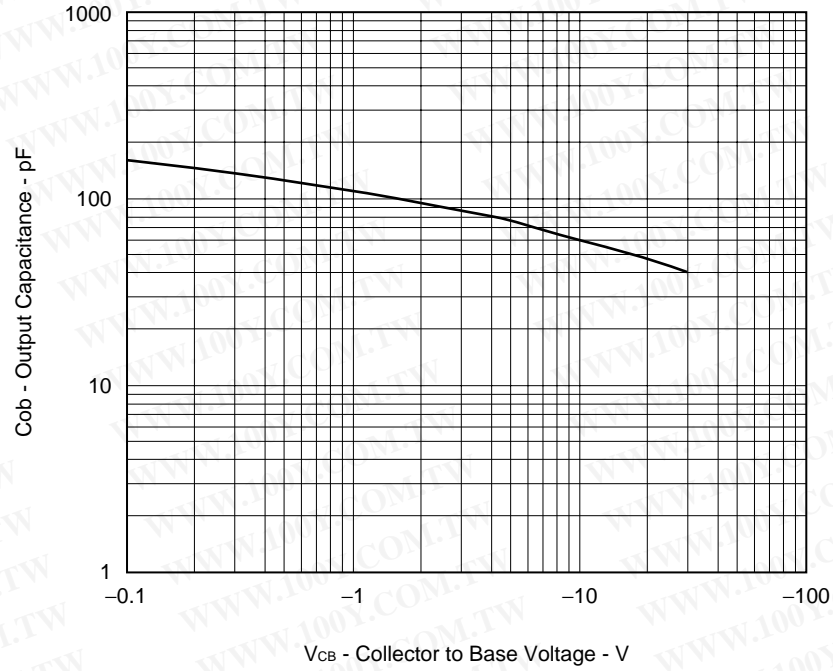
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BASE SATURATION VOLTAGE vs COLLECTOR CURRENT





OUTPUT CAPACITANCE vs COLLECTOR TO BASE VOLTAGE



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**REFERENCE**

Document Name	Document No.
NEC semiconductor device reliability/quality control system	TEI-1202
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	C10535E
Semiconductor device package manual	C10943X
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	X10679E

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Anti-radioactive design is not implemented in this product.